Review of: "nanopatterns and complex 3D structures, as well as the aspect The above characteristics of the ratio regarding these outstanding advantages have also resulted"

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large-scale small/nanopatterns and complex 3D structures, as well as the aspect The above characteristics of the ratio regarding these outstanding advantages have also resulted. This field becomes Especially, nanoelectronic lithography has great potential to set new standards for making miniature, low-cost, and light-weight optics that can be used in many fields of applications.

Conclusion :

Micro- and nano-structures can be used to reduce reflection or guide light in applications such as photovoltaic solar cells, LEDs, or nanoelectronics technology.

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